• 2-A Low-Dropout Voltage Regulator
• Available in 1.5-V, 1.8-V, 2.5-V, 3.3-V Fixed Output and Adjustable Versions
• Open Drain Power-On Reset With 100-ms Delay (TPS752xxQ)
• Open Drain Power-Good (PG) Status Output (TPS754xxQ)
• Dropout Voltage Typically 210 mV at 2 A (TPS75233Q)
• Ultralow 75-µA Typical Quiescent Current
• Fast Transient Response
• 2% Tolerance Over Specified Conditions for Fixed-Output Versions
• 20-Pin TSSOP (PWP) PowerPAD™ Package
• Thermal Shutdown Protection

description

The TPS752xxQ and TPS754xxQ are low dropout regulators with integrated power-on reset and power good (PG) functions respectively. These devices are capable of supplying 2 A of output current with a dropout of 210 mV (TPS75233Q, TPS75433Q). Quiescent current is 75 µA at full load and drops down to 1 µA when the device is disabled. TPS752xxQ and TPS754xxQ are designed to have fast transient response for larger load current changes.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.
Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 210 mV at an output current of 2 A for the TPS75x33Q) and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 75 µA over the full range of output current, 1 mA to 2 A). These two key specifications yield a significant improvement in operating life for battery-powered systems.

The device is enabled when the EN pin is connected to a low-level input voltage. This LDO family also features a sleep mode; applying a TTL high signal to EN (enable) shuts down the regulator, reducing the quiescent current to 1 µA at $T_J = 25^\circ C$.

The RESET (SVS, POR, or power on reset) output of the TPS752xxQ initiates a reset in microcomputer and microprocessor systems in the event of an undervoltage condition. An internal comparator in the TPS752xxQ monitors the output voltage of the regulator to detect an undervoltage condition on the regulated output voltage. When the output reaches 95% of its regulated voltage, RESET goes to a high-impedance state after a 100-ms delay. RESET goes to a logic-low state when the regulated output voltage is pulled below 95% (i.e., over load condition) of its regulated voltage.

The TPS754xxQ has a power good terminal (PG) as an active high, open drain output, which can be used to implement a power-on reset or a low-battery indicator.

The TPS752xxQ or the TPS754xxQ are offered in 1.5-V, 1.8-V, 2.5-V, and 3.3-V fixed-voltage versions and in an adjustable version (programmable over the range of 1.5 V to 5 V). Output voltage tolerance is specified as a maximum of 2% over line, load, and temperature ranges. The TPS752xxQ and the TPS754xxQ families are available in 20 pin TSSOP (PWP) packages.

### AVAILABLE OPTIONS

<table>
<thead>
<tr>
<th>$T_J$</th>
<th>OUTPUT VOLTAGE</th>
<th>TSSOP (PWP)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$-40^\circ C$ to $125^\circ C$</td>
<td>3.3 V</td>
<td>TPS75233QPWP</td>
</tr>
<tr>
<td></td>
<td>2.5 V</td>
<td>TPS75225QPWP</td>
</tr>
<tr>
<td></td>
<td>1.8 V</td>
<td>TPS75218QPWP</td>
</tr>
<tr>
<td></td>
<td>1.5 V</td>
<td>TPS75215QPWP</td>
</tr>
<tr>
<td></td>
<td>Adjustable 1.5 V to 5 V</td>
<td>TPS75201QPWP</td>
</tr>
<tr>
<td></td>
<td></td>
<td>TPS75433QPWP</td>
</tr>
<tr>
<td></td>
<td></td>
<td>TPS75425QPWP</td>
</tr>
<tr>
<td></td>
<td></td>
<td>TPS75418QPWP</td>
</tr>
<tr>
<td></td>
<td></td>
<td>TPS75415QPWP</td>
</tr>
</tbody>
</table>

The TPS75x01 is programmable using an external resistor divider (see application information). The PWP package is available taped and reeled. Add an R suffix to the device type (e.g., TPS75201QPWPR) to indicate tape and reel.

† See application information section for capacitor selection details.

**Figure 1. Typical Application Configuration (For Fixed Output Options)**
functional block diagram—adjustable version

\[ V_{\text{ref}} = 1.1834 \text{ V} \]

\[ V_{\text{OUT}} \]

\[ V_{\text{FB}} \]

\[ V_{\text{GND}} \]

100 ms Delay (for RESET Option)

PG or RESET

External to the device

functional block diagram—fixed-voltage version

\[ V_{\text{ref}} = 1.1834 \text{ V} \]

\[ V_{\text{GND}} \]

100 ms Delay (for RESET Option)
### Terminal Functions (TPS752xxQ)

<table>
<thead>
<tr>
<th>TERMINAL NAME</th>
<th>NO.</th>
<th>I/O</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>EN</td>
<td>5</td>
<td>I</td>
<td>Enable Input</td>
</tr>
<tr>
<td>FB/SENSE</td>
<td>7</td>
<td>I</td>
<td>Feedback input voltage for adjustable device (sense input for fixed-voltage option)</td>
</tr>
<tr>
<td>GND</td>
<td>17</td>
<td></td>
<td>Regulator ground</td>
</tr>
<tr>
<td>GND/HEATSINK</td>
<td>1, 10, 11, 20</td>
<td></td>
<td>Ground/heatsink</td>
</tr>
<tr>
<td>IN</td>
<td>3, 4</td>
<td>I</td>
<td>Input voltage</td>
</tr>
<tr>
<td>NC</td>
<td>2, 12, 13, 14, 15, 16, 18, 19</td>
<td>No connection</td>
<td></td>
</tr>
<tr>
<td>OUTPUT</td>
<td>8, 9</td>
<td>O</td>
<td>Regulated output voltage</td>
</tr>
<tr>
<td>RESET</td>
<td>6</td>
<td>O</td>
<td>Reset output</td>
</tr>
</tbody>
</table>

### Terminal Functions (TPS754xxQ)

<table>
<thead>
<tr>
<th>TERMINAL NAME</th>
<th>NO.</th>
<th>I/O</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>EN</td>
<td>5</td>
<td>I</td>
<td>Enable Input</td>
</tr>
<tr>
<td>FB/SENSE</td>
<td>7</td>
<td>I</td>
<td>Feedback input voltage for adjustable device (sense input for fixed-voltage option)</td>
</tr>
<tr>
<td>GND</td>
<td>17</td>
<td></td>
<td>Regulator ground</td>
</tr>
<tr>
<td>GND/HEATSINK</td>
<td>1, 10, 11, 20</td>
<td></td>
<td>Ground/heatsink</td>
</tr>
<tr>
<td>IN</td>
<td>3, 4</td>
<td>I</td>
<td>Input voltage</td>
</tr>
<tr>
<td>NC</td>
<td>2, 12, 13, 14, 15, 16, 18, 19</td>
<td>No connection</td>
<td></td>
</tr>
<tr>
<td>OUTPUT</td>
<td>8, 9</td>
<td>O</td>
<td>Regulated output voltage</td>
</tr>
<tr>
<td>PG</td>
<td>6</td>
<td>O</td>
<td>Power good output</td>
</tr>
</tbody>
</table>
TPS752xxQ RESET timing diagram

NOTES:
A. $V_{\text{res}}$ is the minimum input voltage for a valid RESET. The symbol $V_{\text{res}}$ is not currently listed within EIA or JEDEC standards for semiconductor symbology.
B. $V_{\text{IT}}$ – Trip voltage is typically 5% lower than the output voltage (95% $V_O$) $V_{\text{IT}}$ to $V_{\text{IT}}$ is the hysteresis voltage.
Notes:

A. $V_{PG}$ is the minimum input voltage for a valid PG. The symbol $V_{PG}$ is not currently listed within EIA or JEDEC standards for semiconductor symbology.

B. $V_{IT-}$ is typically 17% lower than the output voltage ($0.83V_O$). $V_{IT-}$ to $V_{IT+}$ is the hysteresis voltage.
absolute maximum ratings over operating junction temperature range (unless otherwise noted)†

- Input voltage range‡, \( V_I \) .......................... \(-0.3 \) V to \( 6.0 \) V
- Voltage range at \( EN \) ........................................ \(-0.3 \) V to \( 16.5 \) V
- Maximum \( \text{RESET} \) voltage (TPS752xxQ) ......................... \( 16.5 \) V
- Maximum \( \text{PG} \) voltage (TPS754xxQ) .......................... \( 16.5 \) V
- Peak output current .............................................. Internally limited
- Output voltage, \( V_O \) (OUTPUT, FB) ................................. \( 5.5 \) V
- Continuous total power dissipation ............................... See dissipation rating tables
- Operating virtual junction temperature range, \( T_J \) .................. \(-40^\circ C \) to \( 125^\circ C \)
- Storage temperature range, \( T_{stg} \) ................................ \(-65^\circ C \) to \( 150^\circ C \)
- ESD rating, HBM ................................................... \( 2 \) kV

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

‡ All voltage values are with respect to network terminal ground.

DISSIPATION RATING TABLE 1 – FREE-AIR TEMPERATURES

<table>
<thead>
<tr>
<th>PACKAGE</th>
<th>AIR FLOW (CFM)</th>
<th>( T_A &lt; 25^\circ C ) POWER RATING</th>
<th>DERATING FACTOR ABOVE ( T_A = 25^\circ C )</th>
<th>( T_A = 70^\circ C ) POWER RATING</th>
<th>( T_A = 85^\circ C ) POWER RATING</th>
</tr>
</thead>
<tbody>
<tr>
<td>PWP §</td>
<td>0</td>
<td>2.9 W</td>
<td>23.5 mW/°C</td>
<td>1.9 W</td>
<td>1.5 W</td>
</tr>
<tr>
<td></td>
<td>300</td>
<td>4.3 W</td>
<td>34.6 mW/°C</td>
<td>2.8 W</td>
<td>2.2 W</td>
</tr>
<tr>
<td>PWP ¶</td>
<td>0</td>
<td>3 W</td>
<td>23.8 mW/°C</td>
<td>1.9 W</td>
<td>1.5 W</td>
</tr>
<tr>
<td></td>
<td>300</td>
<td>7.2 W</td>
<td>57.9 mW/°C</td>
<td>4.6 W</td>
<td>3.8 W</td>
</tr>
</tbody>
</table>

§ This parameter is measured with the recommended copper heat sink pattern on a 1-layer PCB, 5-in x 5-in PCB, 1 oz. copper, 2-in x 2-in coverage (4 in²).

¶ This parameter is measured with the recommended copper heat sink pattern on a 8-layer PCB, 1.5-in x 2-in PCB, 1 oz. copper with layers 1, 2, 4, 5, 7, and 8 at 5% coverage (0.9 in²) and layers 3 and 6 at 100% coverage (6 in²). For more information, refer to TI technical brief SLMA002.

recommended operating conditions

<table>
<thead>
<tr>
<th></th>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input voltage, ( V_I )#</td>
<td>2.7</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>Output voltage range, ( V_O )</td>
<td>1.5</td>
<td>5</td>
<td>V</td>
</tr>
<tr>
<td>Output current, ( I_O )</td>
<td>0</td>
<td>2.0</td>
<td>A</td>
</tr>
<tr>
<td>Operating virtual junction temperature, ( T_J )</td>
<td>(-40 )</td>
<td>125</td>
<td>°C</td>
</tr>
</tbody>
</table>

# To calculate the minimum input voltage for your maximum output current, use the following equation: \( V_I(\text{min}) = V_O(\text{max}) + V_{DO}(\text{max load}) \).
electrical characteristics over recommended operating junction temperature range ($T_J = -40^\circ C$ to $125^\circ C$), $V_I = V_O(\text{typ}) + 1$ V, $I_O = 1$ mA, $EN = 0$ V, $C_O = 47 \mu F$ (unless otherwise noted)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Output voltage (see Notes 1 and 3)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Adjustable Voltage</td>
<td>$1.5 \leq V_O \leq 5.5$ V, $T_J = 25^\circ C$</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>$1.5 \leq V_O \leq 5.5$ V</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>$T_J = 25^\circ C$, $2.7 &lt; V_{IN} &lt; 5.5$ V</td>
<td>1.5</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>$2.7 &lt; V_{IN} &lt; 5.5$ V</td>
<td>1.47</td>
<td>1.53</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>$2.8 &lt; V_{IN} &lt; 5.5$ V</td>
<td>1.76</td>
<td>1.83</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>$3.5 &lt; V_{IN} &lt; 5.5$ V</td>
<td>2.45</td>
<td>2.55</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>$4.3 &lt; V_{IN} &lt; 5.5$ V</td>
<td>3.23</td>
<td>3.36</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Quiescent current (GND current) (see Note 1)</td>
<td>$T_J = 25^\circ C$, See Note 3</td>
<td>75</td>
<td></td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>Output voltage line regulation ($\Delta V_O/V_O$)</td>
<td>$V_O + 1 \leq V_I \leq 5.5$ V, $T_J = 25^\circ C$,</td>
<td>0.01</td>
<td></td>
<td></td>
<td>%/V</td>
</tr>
<tr>
<td>(see Notes 1 and 2)</td>
<td>$V_O + 1 &lt; V_I &lt; 5.5$ V</td>
<td>0.1</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Load regulation (see Note 3)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>Output noise voltage</td>
<td>$BW = 300 \text{ Hz to } 50 \text{ kHz}$, $V_O = 1.5$ V</td>
<td>60</td>
<td></td>
<td></td>
<td>µVrms</td>
</tr>
<tr>
<td>Output current Limit</td>
<td>$V_O = 0$ V</td>
<td>3.3</td>
<td>4.5</td>
<td></td>
<td>A</td>
</tr>
<tr>
<td>Thermal shutdown junction temperature</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>°C</td>
</tr>
<tr>
<td>Standby current</td>
<td>$EN = V_I$, $T_J = 25^\circ C$,</td>
<td>$1$</td>
<td></td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td></td>
<td>See Note 3</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>FB input current</td>
<td>TPS75x01Q</td>
<td>$FB = 1.5$ V</td>
<td>$-1$</td>
<td>1</td>
<td>µA</td>
</tr>
<tr>
<td>High level enable input voltage</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Low level enable input voltage</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Power supply ripple rejection (see Note 2)</td>
<td>$f = 100$ Hz, $C_O = 100 \mu F$, $T_J = 25^\circ C$, $I_O = 2$ A</td>
<td>60</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Reset (TPS752xxQ)</td>
<td>Minimum input voltage for valid $\text{RESET}$</td>
<td>$I_O(\text{RESET}) = 300 \mu A$, $V(\text{RESET}) \leq 0.8$ V</td>
<td>1</td>
<td>1.3</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>Trip threshold voltage</td>
<td>$V_O$ decreasing</td>
<td>92</td>
<td>98</td>
<td>%$V_O$</td>
</tr>
<tr>
<td></td>
<td>Hysteresis voltage</td>
<td>Measured at $V_O$</td>
<td>0.5</td>
<td></td>
<td>%$V_O$</td>
</tr>
<tr>
<td></td>
<td>Output low voltage</td>
<td>$V_I = 2.7$ V,</td>
<td>0.15</td>
<td>0.4</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_O(\text{RESET}) = 1$ mA</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>Leakage current</td>
<td>$V(\text{RESET}) = 5.5$ V</td>
<td>1</td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td></td>
<td>RESET time-out delay</td>
<td></td>
<td>100</td>
<td></td>
<td>ms</td>
</tr>
</tbody>
</table>

NOTES: 1. Minimum IN operating voltage is 2.7 V or $V_O(\text{typ}) + 1$ V, whichever is greater. Maximum IN voltage 5.5 V.
2. If $V_O \leq 1.8$ V then $V_{imin} = 2.7$ V, $V_{imax} = 5.5$ V:

$$\text{Line Reg. (mV)} = \frac{V_O \left( V_{imax} - 2.7 \right)}{100} \times 1000$$

If $V_O \geq 2.5$ V then $V_{imin} = V_O + 1$ V, $V_{imax} = 5.5$ V:

$$\text{Line Reg. (mV)} = \frac{V_O \left( V_{imax} - \left( V_O + 1 \right) \right)}{100} \times 1000$$

3. $I_O = 1$ mA to 2 A
electrical characteristics over recommended operating junction temperature range (T_J = –40°C to 125°C), V_I = V_O(typ) + 1 V, I_O = 1 mA, EN = 0 V, C_O = 47 µF (unless otherwise noted) (continued)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>PG (TPS754xxQ)</td>
<td>Minimum input voltage for valid PG</td>
<td>I_O(PG) = 300 µA</td>
<td>V(PG) ≤ 0.8 V</td>
<td>1.1</td>
<td>1.3 V</td>
</tr>
<tr>
<td></td>
<td>Trip threshold voltage</td>
<td></td>
<td></td>
<td>80</td>
<td>86 %V_O</td>
</tr>
<tr>
<td></td>
<td>Hysteresis voltage</td>
<td></td>
<td></td>
<td>0.5</td>
<td>%V_O</td>
</tr>
<tr>
<td></td>
<td>Output low voltage</td>
<td></td>
<td></td>
<td>0.15</td>
<td>0.4 V</td>
</tr>
<tr>
<td></td>
<td>Leakage current</td>
<td></td>
<td></td>
<td>1</td>
<td>µA</td>
</tr>
<tr>
<td></td>
<td>Input current (EN)</td>
<td></td>
<td></td>
<td>EN = V_I</td>
<td>–1</td>
</tr>
<tr>
<td></td>
<td>High level EN input voltage</td>
<td></td>
<td></td>
<td>EN = 0 V</td>
<td>–1</td>
</tr>
<tr>
<td></td>
<td>Low level EN input voltage</td>
<td></td>
<td></td>
<td></td>
<td>0.7 V</td>
</tr>
<tr>
<td></td>
<td>Dropout voltage (3.3 V Output) (see Note 4)</td>
<td></td>
<td></td>
<td>I_O = 2 A, T_J = 25°C</td>
<td>V_I = 3.2 V,</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td>I_O = 2 A, V_I = 3.2 V</td>
<td>400</td>
</tr>
</tbody>
</table>

NOTE 4: IN voltage equals V_O(Typ) – 100 mV; TPS75x15Q, TPS75x18Q and TPS75x25Q dropout voltage limited by input voltage range limitations (i.e., TPS75x33Q input voltage needs to drop to 3.2 V for purpose of this test).

Table of Graphs

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| | vs Junction temperature | 4, 5, |
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TYPICAL CHARACTERISTICS

TPS75x33Q
OUTPUT VOLTAGE
vs
OUTPUT CURRENT

Figure 2

TPS75x15Q
OUTPUT VOLTAGE
vs
OUTPUT CURRENT

Figure 3

TPS75x33Q
OUTPUT VOLTAGE
vs
JUNCTION TEMPERATURE

Figure 4

TPS75x15Q
OUTPUT VOLTAGE
vs
JUNCTION TEMPERATURE

Figure 5
TPS75xxxQ
GROUND CURRENT
vs
JUNCTION TEMPERATURE

Ground Current – µA
90
85
80
75
70
65
60
55
50
40
10
60
110
160

Tj – Junction Temperature – °C

Figure 6

TPS75xxxQ
POWER SUPPLY RIPPLE REJECTION
vs
FREQUENCY

PSRR – Power Supply Ripple Rejection – dB
100
90
80
70
60
50
40
30
20
10
0

f – Frequency – Hz

f1 = 4.3 V
C0 = 100 µF
I0 = 1 mA
Tj = 25°C

f1 = 4.3 V
C0 = 100 µF
I0 = 2 A
Tj = 25°C

Figure 7

TPS75x33Q
OUTPUT SPECTRAL NOISE DENSITY
vs
FREQUENCY

Vn – Voltage Noise – nV/√Hz
2
1.8
1.6
1.4
1.2
1.0
0.8
0.6
0.4
0.2
0

f – Frequency – Hz

f1 = 4.3 V
V0 = 3.3 V
C0 = 100 µF
Tj = 25°C

f1 = 4.3 V
C0 = 100 µF
I0 = 2 A

Figure 8

TPS75x33Q
OUTPUT IMPEDANCE
vs
FREQUENCY

Z0 – Output Impedance – Ω
10^1
10^0
10^{-1}
10^{-2}

f – Frequency – Hz

C0 = 100 µF
I0 = 1 mA

C0 = 100 µF
I0 = 2 A

Figure 9
TPS75201Q, TPS75215Q, TPS75218Q, TPS75225Q, TPS75233Q WITH RESET
TPS75401Q, TPS75415Q, TPS75418Q, TPS75425Q, TPS75433Q WITH POWER GOOD
FAST-TRANSIENT-RESPONSE 2-A LOW-DROPOUT VOLTAGE REGULATORS

TYPICAL CHARACTERISTICS

**Figure 10**
TPS75x01Q
**DROPOUT VOLTAGE**
vs
**INPUT VOLTAGE**

![Graph showing dropout voltage vs input voltage for TPS75x01Q regulators.](image)

- **V DO** – Dropout Voltage – mV
- **V I** – Input Voltage – V
- **I O** = 2 A
- **T J = 125°C**
- **T J = 25°C**
- **T J = –40°C**

**Figure 11**
TPS75x33Q
**DROPOUT VOLTAGE**
vs
**JUNCTION TEMPERATURE**

![Graph showing dropout voltage vs junction temperature for TPS75x33Q regulators.](image)

- **V DO** – Dropout Voltage – mV
- **T J** – Junction Temperature – °C
- **I O** = 2 A
- **I O** = 1.5 A
- **I O** = 0.5 A

**Figure 12**
**INPUT VOLTAGE (MIN)**
vs
**OUTPUT VOLTAGE**

![Graph showing input voltage vs output voltage for TPS75x15Q regulators.](image)

- **V I** – Input Voltage (Min) – V
- **V O** – Output Voltage – V
- **I O** = 2 A
- **I O** = 2 A
- **I O** = 1.5 A
- **I O** = 0.5 A
- **T A = 25°C**
- **T A = 125°C**
- **T A = –40°C**

**Figure 13**
**TPS75x15Q**
**LINE TRANSIENT RESPONSE**

![Graph showing line transient response for TPS75x15Q regulators.](image)

- **V O – Change in Output Voltage – mV**
- **t** – Time – ms
- **I O = 2 A**
- **C O = 100 µF**
- **V O = 1.5 V**
- **dv/dt = 1 V/µs**
TPS75x15Q
LOAD TRANSIENT RESPONSE

\( I_O = 2 \text{ A} \)
\( C_L = 100 \mu\text{F} \) (Tantalum)
\( V_O = 1.5 \text{ V} \)

Figure 14

TPS75x33Q
APPLICATION CIRCUIT

\( I_O = 2 \text{ A} \)
\( C_O = 100 \mu\text{F} \) (Tantalum)
\( V_O = 3.3 \text{ V} \)

Figure 16

TPS75x33Q
LINE TRANSIENT RESPONSE

\( I_O = 2 \text{ A} \)
\( C_O = 100 \mu\text{F} \)
\( V_I = 4.3 \text{ V} \)
\( T_J = 25 \degree \text{C} \)
\( \frac{dv}{dt} = \frac{1 \text{ V}}{10 \mu\text{s}} \)

\( V_O = 3.3 \text{ V} \)

Figure 15

TPS75x33Q
OUTPUT VOLTAGE VS TIME (STARTUP)

\( V_I = 4.3 \text{ V} \)
\( T_J = 25 \degree \text{C} \)

\( V_O = 3.3 \text{ V} \)

Figure 17
**Typical Characteristics**

Figure 18. Test Circuit for Typical Regions of Stability (Figures 19 and 20) (Fixed Output Options)

![Test Circuit Diagram](image)

**Figure 19**

<table>
<thead>
<tr>
<th>ESR – Equivalent series resistance – Ω</th>
<th>Vₒ = 3.3 V</th>
<th>Cₒ = 100 µF</th>
<th>Vᵢ = 4.3 V</th>
<th>Tᵢ = 25°C</th>
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Region of Stability

**Figure 20**

<table>
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<th>ESR – Equivalent series resistance – Ω</th>
<th>Vₒ = 3.3 V</th>
<th>Cₒ = 47 µF</th>
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Region of Instability

† Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to Cₒ.
APPLICATION INFORMATION

The TPS752xxQ or TPS754xxQ families include four fixed-output voltage regulators (1.5 V, 1.8 V, 2.5 V and 3.3 V), and an adjustable regulator, the TPS75x01Q (adjustable from 1.5 V to 5 V).

minimum load requirements

The TPS752xxQ and TPS754xxQ families are stable even at no load; no minimum load is required for operation.

pin functions

enable (EN)

The EN terminal is an input which enables or shuts down the device. If EN is a logic high, the device will be in shutdown mode. When EN goes to logic low, then the device will be enabled.

power good (PG) (TPS754xxQ)

The PG terminal is an open drain, active high output that indicates the status of VO (output of the LDO). When VO reaches 83% of the regulated voltage, PG will go to a high impedance state. It will go to a low-impedance state when VO falls below 83% (i.e. over load condition) of the regulated voltage. The open drain output of the PG terminal requires a pullup resistor.

sense (SENSE)

The SENSE terminal of the fixed-output options must be connected to the regulator output, and the connection should be as short as possible. Internally, SENSE connects to a high-impedance wide-bandwidth amplifier through a resistor-divider network and noise pickup feeds through to the regulator output. It is essential to route the SENSE connection in such a way to minimize/avoid noise pickup. Adding RC networks between the SENSE terminal and VO to filter noise is not recommended because it may cause the regulator to oscillate.

feedback (FB)

FB is an input terminal used for the adjustable-output options and must be connected to an external feedback resistor divider. The FB connection should be as short as possible. It is essential to route it in such a way to minimize/avoid noise pickup. Adding RC networks between FB terminal and VO to filter noise is not recommended because it may cause the regulator to oscillate.

reset (RESET) (TPS752xxQ)

The RESET terminal is an open drain, active low output that indicates the status of VO. When VO reaches 95% of the regulated voltage, RESET will go to a low-impedance state after a 100-ms delay. RESET will go to a high-impedance state when VO is below 95% of the regulated voltage. The open-drain output of the RESET terminal requires a pullup resistor.

GND/HEATSINK

All GND/HEATSINK terminals are connected directly to the mount pad for thermal-enhanced operation. These terminals could be connected to GND or left floating.

input capacitor

For a typical application, an input bypass capacitor (0.22 µF – 1 µF) is recommended for device stability. This capacitor should be as close to the input pins as possible. For fast transient condition where droop at the input of the LDO may occur due to high inrush current, it is recommended to place a larger capacitor at the input as well. The size of this capacitor is dependant on the output current and response time of the main power supply, as well as the distance to the load (LDO).
APPLICATION INFORMATION

output capacitor

As with most LDO regulators, the TPS752xxQ and TPS754xxQ require an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 47 µF and the ESR (equivalent series resistance) must be between 100 mΩ and 10 Ω. Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described in this section. Larger capacitors provide a wider range of stability and better load transient response.

This information, along with the ESR graphs, is included to assist in selection of suitable capacitance for the user’s application. When necessary to achieve low height requirements along with high output current and/or high load capacitance, several higher ESR capacitors can be used in parallel to meet these guidelines.

ESR and transient response

LDOs typically require an external output capacitor for stability. In fast transient response applications, capacitors are used to support the load current while LDO amplifier is responding. In most applications, one capacitor is used to support both functions.

Besides its capacitance, every capacitor also contains parasitic impedances. These parasitic impedances are resistive as well as inductive. The resistive impedance is called equivalent series resistance (ESR), and the inductive impedance is called equivalent series inductance (ESL). The equivalent schematic diagram of any capacitor can therefore be drawn as shown in Figure 21.

![Figure 21. ESR and ESL](image-url)
APPLICATION INFORMATION

In most cases one can neglect the effect of inductive impedance ESL. Therefore, the following application focuses mainly on the parasitic resistance ESR.

Figure 22 shows the output capacitor and its parasitic impedances in a typical LDO output stage.

In steady state (dc state condition), the load current is supplied by the LDO (solid arrow) and the voltage across the capacitor is the same as the output voltage \( V(C_O) = V_O \). This means no current is flowing into the \( C_O \) branch. If \( I_O \) suddenly increases (transient condition), the following occurs:

- The LDO is not able to supply the sudden current need due to its response time \( t_1 \) in Figure 24. Therefore, capacitor \( C_O \) provides the current for the new load condition (dashed arrow). \( C_O \) now acts like a battery with an internal resistance, ESR. Depending on the current demand at the output, a voltage drop will occur at \( R_{ESR} \). This voltage is shown as \( V_{ESR} \) in Figure 23.

- When \( C_O \) is conducting current to the load, initial voltage at the load will be \( V_O = V(C_O) - V_{ESR} \). Due to the discharge of \( C_O \), the output voltage \( V_O \) will drop continuously until the response time \( t_1 \) of the LDO is reached and the LDO will resume supplying the load. From this point, the output voltage starts rising again until it reaches the regulated voltage. This period is shown as \( t_2 \) in Figure 24.

The figure also shows the impact of different ESRs on the output voltage. The left brackets show different levels of ESRs where number 1 displays the lowest and number 3 displays the highest ESR.

From above, the following conclusions can be drawn:

- The higher the ESR, the larger the droop at the beginning of load transient.
- The smaller the output capacitor, the faster the discharge time and the bigger the voltage droop during the LDO response period.
APPLICATION INFORMATION

conclusion

To minimize the transient output droop, capacitors must have a low ESR and be large enough to support the minimum output voltage requirement.

![Diagram showing correlation of different ESRs and their influence to the regulation of VO at a load step from low-to-high output current.]

Figure 23. Correlation of Different ESRs and Their Influence to the Regulation of VO at a Load Step From Low-to-High Output Current
programming the TPS75x01Q adjustable LDO regulator

The output voltage of the TPS75x01Q adjustable regulator is programmed using an external resistor divider as shown in Figure 24. The output voltage is calculated using:

\[ V_O = V_{ref} \times \left( 1 + \frac{R1}{R2} \right) \]  \hspace{1cm} (1)

Where:

\[ V_{ref} = 1.1834 \text{ V typ (the internal reference voltage)} \]

Resistors R1 and R2 should be chosen for approximately 40-\( \mu \)A divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose \( R2 = 30.1 \text{ k}\Omega \) to set the divider current at 40 \( \mu \)A and then calculate R1 using:

\[ R1 = \left( \frac{V_O}{V_{ref}} - 1 \right) \times R2 \] \hspace{1cm} (2)

NOTE: To reduce noise and prevent oscillation, R1 and R2 need to be as close as possible to the FB/SENSE terminal.

![Figure 24. TPS75x01Q Adjustable LDO Regulator Programming](image-url)
APPLICATION INFORMATION

regulator protection

The TPS752xxQ and TPS754xxQ PMOS-pass transistors has a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS752xxQ and TPS754xxQ also feature internal current limiting and thermal protection. During normal operation, the TPS752xxQ and TPS754xxQ limit output current to approximately 3.3 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C(typ), thermal-protection circuitry shuts it down. Once the device has cooled below 130°C(typ), regulator operation resumes.

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125°C; the maximum junction temperature should be restricted to 125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D\text{(max)}}$, and the actual dissipation, $P_D$, which must be less than or equal to $P_{D\text{(max)}}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D\text{(max)}} = \frac{T_{J\text{max}} - T_A}{R_{\theta JA}}$$

Where:

- $T_{J\text{max}}$ is the maximum allowable junction temperature
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, i.e., 34.6°C/W for the 20-terminal PWP with no airflow (see Table 1).
- $T_A$ is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = (V_I - V_O) \times I_O$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.
THERMAL INFORMATION
	hermally enhanced TSSOP-20 (PWP – PowerPad™)

The thermally enhanced PWP package is based on the 20-pin TSSOP, but includes a thermal pad [see Figure 25(c)] to provide an effective thermal contact between the IC and the PWB.

Traditionally, surface mount and power have been mutually exclusive terms. A variety of scaled-down TO220-type packages have leads formed as gull wings to make them applicable for surface-mount applications. These packages, however, suffer from several shortcomings: they do not address the very low profile requirements (<2 mm) of many of today’s advanced systems, and they do not offer a pin-count high enough to accommodate increasing integration. On the other hand, traditional low-power surface-mount packages require power-dissipation derating that severely limits the usable range of many high-performance analog circuits.

The PWP package (thermally enhanced TSSOP) combines fine-pitch surface-mount technology with thermal performance comparable to much larger power packages.

The PWP package is designed to optimize the heat transfer to the PWB. Because of the very small size and limited mass of a TSSOP package, thermal enhancement is achieved by improving the thermal conduction paths that remove heat from the component. The thermal pad is formed using a lead-frame design (patent pending) and manufacturing technique to provide the user with direct connection to the heat-generating IC. When this pad is soldered or otherwise coupled to an external heat dissipator, high power dissipation in the ultrathin, fine-pitch, surface-mount package can be reliably achieved.

Figure 25. Views of Thermally Enhanced PWP Package

Because the conduction path has been enhanced, power-dissipation capability is determined by the thermal considerations in the PWB design. For example, simply adding a localized copper plane (heat-sink surface), which is coupled to the thermal pad, enables the PWP package to dissipate 2.5 W in free air (reference Figure 27(a), 8 cm² of copper heat sink and natural convection). Increasing the heat-sink size increases the power dissipation range for the component. The power dissipation limit can be further improved by adding airflow to a PWB/IC assembly (see Figures 26 and 27). The line drawn at 0.3 cm² in Figures 26 and 27 indicates performance at the minimum recommended heat-sink size, illustrated in Figure 29.
thermally enhanced TSSOP-20 (PWP – PowerPad™) (continued)

The thermal pad is directly connected to the substrate of the IC, which for the TPS752xxQPWP and TPS754xxQPWP series is a secondary electrical connection to device ground. The heat-sink surface that is added to the PWP can be a ground plane or left electrically isolated. In TO220-type surface-mount packages, the thermal connection is also the primary electrical connection for a given terminal which is not always ground. The PWP package provides up to 16 independent leads that can be used as inputs and outputs (Note: leads 1, 10, 11, and 20 are internally connected to the thermal pad and the IC substrate).

---

**Figure 26**

**THERMAL RESISTANCE**

**vs**

**COPPER HEAT-SINK AREA**

---

---
THERMAL INFORMATION

thermally enhanced TSSOP-20 (PWP – PowerPad™) (continued)

Figure 27. Power Ratings of the PWP Package at Ambient Temperatures of 25°C, 55°C, and 105°C
THERMAL INFORMATION

thermally enhanced TSSOP-20 (PWP – PowerPad™) (continued)

Figure 28 is an example of a thermally enhanced PWB layout for use with the new PWP package. This board configuration was used in the thermal experiments that generated the power ratings shown in Figure 26 and Figure 27. As discussed earlier, copper has been added on the PWB to conduct heat away from the device. $R_{\theta JA}$ for this assembly is illustrated in Figure 26 as a function of heat-sink area. A family of curves is included to illustrate the effect of airflow introduced into the system.

**Figure 28. PWB Layout (Including Copper Heatsink Area) for Thermally Enhanced PWP Package**

From Figure 26, $R_{\theta JA}$ for a PWB assembly can be determined and used to calculate the maximum power-dissipation limit for the component/PWB assembly, with the equation:

$$P_{D(max)} = \frac{T_{J max} - T_A}{R_{\theta JA(system)}}$$  \hspace{1cm} (5)

Where:

- $T_{J max}$ is the maximum specified junction temperature (150°C absolute maximum limit, 125°C recommended operating limit) and $T_A$ is the ambient temperature.

$P_{D(max)}$ should then be applied to the internal power dissipated by the TPS75233QPWP regulator. The equation for calculating total internal power dissipation of the TPS75233QPWP is:

$$P_{D(total)} = (V_I - V_O) \times I_O + V_I \times I_Q$$  \hspace{1cm} (6)

Since the quiescent current of the TPS75233QPWP is very low, the second term is negligible, further simplifying the equation to:

$$P_{D(total)} = (V_I - V_O) \times I_Q$$  \hspace{1cm} (7)

For the case where $T_A = 55°C$, airflow = 200 ft/min, copper heat-sink area = 4 cm², the maximum power-dissipation limit can be calculated. First, from Figure 26, we find the system $R_{\theta JA}$ is 50°C/W; therefore, the maximum power-dissipation limit is:

$$P_{D(max)} = \frac{T_{J max} - T_A}{R_{\theta JA(system)}} = \frac{125°C - 55°C}{50°C/W} = 1.4 \text{ W}$$  \hspace{1cm} (8)

---

Board thickness 62 mils
Board size 3.2 in. × 3.2 in.
Board material FR4
Copper trace/heat sink 1 oz
Exposed pad mounting 63/67 tin/lead solder
thermally enhanced TSSOP-20 (PWP – PowerPad™) (continued)

If the system implements a TPS75233QPWP regulator, where \( V_I = 5 \) V and \( I_O = 800 \) mA, the internal power dissipation is:

\[
P_{D\text{(total)}} = (V_I - V_O) \times I_O = (5 - 3.3) \times 0.8 = 1.36 \text{ W}
\]  

(9)

Comparing \( P_{D\text{(total)}} \) with \( P_{D\text{(max)}} \) reveals that the power dissipation in this example does not exceed the calculated limit. When it does, one of two corrective actions should be made: raising the power-dissipation limit by increasing the airflow or the heat-sink area, or lowering the internal power dissipation of the regulator by reducing the input voltage or the load current. In either case, the above calculations should be repeated with the new system parameters.

mounting information

The primary requirement is to complete the thermal contact between the thermal pad and the PWB metal. The thermal pad is a solderable surface and is fully intended to be soldered at the time the component is mounted. Although voiding in the thermal-pad solder-connection is not desirable, up to 50% voiding is acceptable. The data included in Figures 26 and 27 is for soldered connections with voiding between 20% and 50%. The thermal analysis shows no significant difference resulting from the variation in voiding percentage.

Figure 29 shows the solder-mask land pattern for the PWP package. The minimum recommended heat-sink area is also illustrated. This is simply a copper plane under the body extent of the package, including metal routed under terminals 1, 10, 11, and 20.
## Packaging Information

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<th>Package Type</th>
<th>Package Drawing</th>
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(1) The marketing status values are defined as follows:
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(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusions.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. Falls within JEDEC MO-153.

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